L64733C/L64734 Tuner and **Satellite Receiver Chipset**

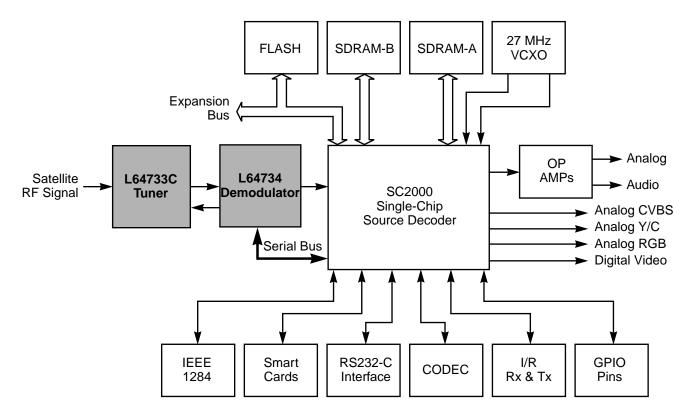
Datasheet



The L64733C/734 chipset is designed for satellite broadcast digital TV. It is compliant with the European digital video broadcast (DVB-S) standard, as well as the technical specifications for DSS systems. The L64733C/734 chipset forms a complete "L-band-to-bits" system.

A typical application of the L64733C/734 chipset is satellite digital TV reception in accordance with the ETS 300 421 standard. Figure 1 shows the L64733C/734 chipset satellite receiver implemented in a typical satellite receiver set-top decoder.

Figure 1 **Set-Top Box Block Diagram**



The L64733C Tuner IC directly down-converts the satellite signal from L-band to baseband; it includes an on-chip synthesizer. Using frequency information programmed into its configuration registers, the L64734 Satellite Receiver generates control signals for the L64733C synthesizer. The L64734 also controls the programming of the low-pass filters on the

February 2001 1 L64733C and generates dual automatic gain control (AGC) voltages for the two-stage automatic gain control on the L64733C. A simplified chipset block diagram is shown in Figure 2.

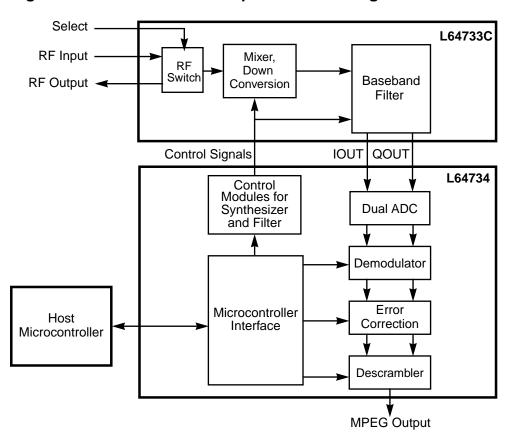


Figure 2 L64733C/734 Simplified Block Diagram

Figure 3 shows a more detailed chipset block diagram.

The L64733C accepts the RF In L-Band signal input from the satellite low noise block (LNB) feed. The L64733C handles a fully loaded raster of transponder signals from 925 MHz to 2175 MHz. RF In is internally matched to 75 Ω ; it requires no matching network between the cable connector and the L64733C input pins, except for a DC-blocking capacitor. The L64733C uses the L64734 INSEL signal to select the appropriate RF function (Normal or Loop-Through Mode).

L64733C Xtal Phase Charge To external by 8 Detect. Pump Loop Filter Osc 4-7.26 MHz Quadrature Down-Converter RF In RF Amp Switch RF Out **◄** Tank Fc 90° Circuit ÷32/33 LOBUF ÷1/2 LODIV **FDOUB PSOUT** FLCLK QOUT IOUT AGC2 AGC1 INSEL MOD L64734 Filter **AGC** Control Control Synthesizer Control Module Module Carrier Loop Control **BPSK/QPSK** Timing Loop **Demodulator** Control Interpolator/Decimation Dual Matched Output 1/T ADC Filter Filter Control Microcontroller Data and Address Bus Clk (from L64734 External Microcontroller Interface **FEC Decoder Pipeline** on-chip PLL) Microcontroller Data and Address Bus Channel Output Reed-Reed-Viterbi Convolutional (MPEG-2 Solomon Solomon Descrambler Decoder Deinterleaver Synchronizer Transport Decoder Stream) Viterbi Synchronizer

Figure 3 Detailed Chipset Block Diagram

The RF signal is sent to a variable gain stage controlled by the L64734 AGC1 signal. The L64734 adjusts AGC1 in conjunction with AGC2 to maximize the SNR of the RF In signal while maintaining proper levels at the baseband outputs (IOUT and QOUT). The signal then is fed to two mixers in the quadrature demodulator. The mixers are fed with local oscillator signals that are offset by 90 degrees from one another. The quadrature demodulator converts the frequency of the RF In signal directly to baseband while splitting the signal into quadrature I and Q signal paths.

The baseband signals pass through a pair of variable gain amplifiers, controlled through the AGC2 pin by the L64734. The signals then pass through a pair of seventh-order filters for antialiasing. The filter shape is seventh-order Butterworth, followed by a single-pole delay equalizer. The L64734 FLCLK signal controls the filter cutoff frequency, which is related to the baud rate. The filtered baseband output signals are fed to differential output stages at IOUTp, IOUTn, QOUTp, and QOUTn.

The baseband outputs of the L64733C are sent to the L64734 to be digitized by the analog-to-digital converter (ADC). Then, they are sent to a BPSK/QPSK demodulator, filtered, and sent to the L64734 forward error correction (FEC) decoder pipeline, which outputs an MPEG-2 transport stream.

The frequency synthesizer functionality is split between the L64733C and L64734. The Synthesizer Control Module resides on the L64734 and generates control signals for the L64733C Tuner IC frequency synthesizer. The Synthesizer Control Module also contains programmable counters for the synthesizer feedback loop.

The L64733C provides analog functions for the frequency synthesizer, the RF local oscillator, and the crystal reference oscillator. Tuning oscillator signals are generated for the mixers in the 925–2175 MHz range, with a 0.625 MHz step size when using a 5 MHz crystal reference. The on-chip VCO tuning frequency is 543–1088 MHz. To tune channels from 925–1086 MHz, the L64734 disables the frequency doubler (X2 block) on the L64733C. To tune channels from 1086–2175 MHz, the L64734 enables the frequency doubler.

The L64733C can improve half-harmonic rejection. It requires special programming of the frequency doubler control pin (FDOUB), which now

has 3-state operation (see the "Synthesizer Control Interface" section on page 20).

The VCO requires an external resonant tank circuit, which includes varactor diodes to vary the frequency of oscillation.

The VCO signal is fed to the Prescaler block before being passed deferentially through the PSOUTp and PSOUTn pins to the L64734. The L64734 MODp and MODn differential signals control the divider ratio for the Prescaler block. The L64734 dynamically changes the divide ratio to ensure that the tuning step size is not affected by the divider. The L64734 contains programmable counters to further divide the signal frequency before it is fed back to the L64733C through the PLLINp and PLLINn pins. The crystal reference oscillator frequency is divided by eight and fed to the phase detector. The phase detector generates a current signal proportional to the difference in phase between PLLINp. PLLINn, and the divided crystal frequency. A charge pump circuit generates current that controls pins CP and FB, and an external transistor to buffer the L64733C against the tuning voltage (28 V). The current is passed through a discrete loop filter and is converted to a tuning voltage that drives the external varactor diodes for the VCO tank circuit. A frequency controlled loop is formed. Changing the frequency divider ratios in the L64734 registers varies the VCO frequency. See Figure 7, on page 23, for more details regarding the external circuitry for the VCO, crystal oscillator, charge pump, tank circuitry, and frequency-controlled loop.

The chipset provides maximum integration and flexibility for system designers at a minimum cost. The number of external components required to build a system is minimal because the synthesizer, variable rate filters, and clock and carrier loops are integrated into the two devices.

Features and Benefits

The following subsections provide a list of system and chipset features.

System Features

- Direct down-conversion
- Integrated programmable cut-off low-pass filters for variable-rate operation
- Dual AGC for optimizing performance with respect to intermodulation and noise
- Integrated synthesizer
- Integrated quadrature amplitude and phase imbalance compensation
- RF Loop-Through

Chipset Features

- DVB and DSS system specifications support
- BPSK/QPSK demodulation rates from 1 to 45 Mbaud
- Matched filter (square root raised cosine filter with roll off factor of 20% or 35%)
- Antialiasing filters for operation from 1 to 45 MBaud without switching external SAW filters or the need for low-pass filters
- On-chip digital clock synchronization
- On-chip digital carrier synchronization, featuring a frequency sweep capability for signal acquisition
- Autoacquisition demodulator mode and tuner control through an on-chip microcontroller
- Integrated Phase-Locked Loop (PLL) for clock synthesis, allowing the use of a fundamental mode crystal
- Fast channel switching mode
- Power estimation for AGC
- Programmable Viterbi decoder module for rates 1/2, 2/3, 3/4, 5/6, 6/7, and 7/8

- (204/188), (146/130) Reed-Solomon decoder
- Autosynchronization for Viterbi decoder
- Programmable synchronization for deinterleaver, Reed-Solomon decoder, and descrambler
- Bit error monitoring for channel performance measurements
- Deinterleaver (DVB and DSS)
- Serial host interface compatible with the LSI Logic Serial Control bus interface
- Power-down mode
- On-chip dual differential 6-bit ADCs
- Supports Synchronous Parallel Interface protocol for FEC data output

Chipset Interconnections

Figure 4 illustrates the signals between the L64733C and L64734.

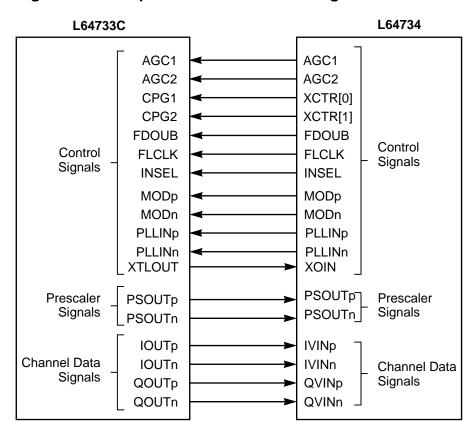
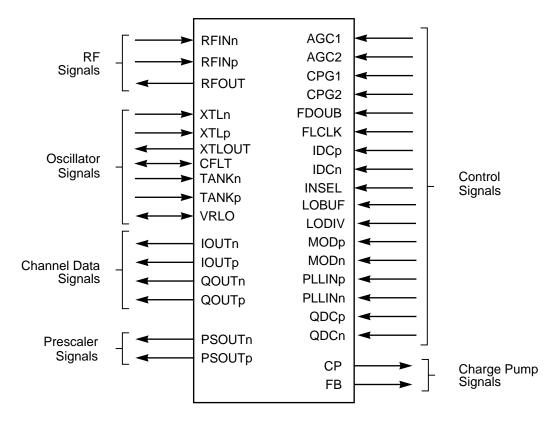


Figure 4 Chipset Interconnection Diagram

L64733C Signal Descriptions

This section describes the L64733C signals. Figure 5 shows the interface diagram of the L64733C. An "n" suffix (for example, ERROROUTn) designates an active LOW signal. Names of differential signals are designated with a "p" suffix for the noninverting side (for example, QOUTp), and with an "n" suffix for the inverting side (for example, QOUTn).

Figure 5 L64733C Interface Diagram



As shown in Figure 5, the L64733C has the following major interfaces:

- RF
- Oscillator
- Channel Data
- Prescaler
- Control
- Charge Pump

The following signal descriptions are listed according to the major interface groups.

RF Signals

The L64733C can accept an RF input signal and loop it to RFOUT, as determined by an on-chip RF switch.

RFINp, RFINn RF Input

Input

The RFIN differential signals form the 75 Ω input. Connect the RFINp signal through a series 100 pF capacitor to a 75 Ω F video connector and the RFINn signal through a series 75 Ω resistor and 100 pF capacitor to ground.

RFOUT RF Output

Output

The RFOUT signal is a 75 Ω output that is active when the INSEL input is deasserted. When active, the signal at RFOUT is a copy of the RFIN signal.

Oscillator Signals

The L64733C has two internal oscillators, a crystal oscillator and a tank oscillator.

CFLT Bias Voltage Bypass

Bidirectional

Connect the CFLT pin as shown in Figure 7 on page 23.

TANKp, TANKn

Oscillator Tank Port

Input

Connect the TANKp and TANKn pins as shown in

Figure 7 on page 23.

VRLO Local Oscillator Regulator Bypass

Bidirectional

Connect the VRLO pin as shown in Figure 7 on page 23.

XTLp, XTLn Crystal Oscillator Port

Input

Connect the XTLp and XTLn pins as shown in Figure 7

on page 23.

XTLOUT Crystal Out

Output

This signal provides a buffered clock reference frequency

for driving the L64734 XOIN pin.

Channel Data Signals

The following signals are the channel data signals from the L64733C to the L64734.

IOUTp, IOUTn I Channel Baseband Data

Output

The IOUT differential signals form the in-phase data provided to the L64734.

QOUTp, QOUTn

Q Channel Baseband Data

Output

The QOUT differential signals form the quadrature-phase data provided to the L64734.

Prescaler Signals

The following signals are the prescaler outputs from the L64733C to the L64734.

PSOUTp, PSOUTn

Prescaler Output

When the LOBUF signal is LOW, the PSOUT differential signals are the L64733C prescaler outputs.

When LOBUF is HIGH, the Local Oscillator (LO) buffer (50 Ω) feeds the PSOUT differential signals.

The programmable counters on the L64734 are clocked on the rising edge of the PSOUT signal.

Control Signals

The following signals, some of which are generated by the L64734 IC, control the mode of operation of the L64733C IC.

AGC1 Automatic Gain Control 1 Input

The AGC1 signal is a high-impedance input from the L64734 that controls RF AGC circuitry. The AGC1 voltage has a range of 0.5 V to 4.8 V.

AGC2 Automatic Gain Control 2

The AGC2 signal is a high-impedance input from the L64734 that controls RF AGC circuitry.

CPG[2:1] Charge Pump Gain

Input

Input

The CPG[2:1] signals set the charge pump gain according to the table below.

Charge Pump Current (typ), mA

| | | • | |
|------|------|---------|--------|
| CPG1 | CPG2 | FB HIGH | FB LOW |
| 0 | 0 | 0.1 | -0.1 |
| 0 | 1 | 0.3 | -0.3 |
| 1 | 0 | 0.6 | -0.6 |
| 1 | 1 | 1.8 | -1.8 |

FDOUB Frequency Doubler

Input

When FDOUB is asserted, the L64733C local oscillator frequency is internally doubled and fed to the mixers. When FDOUB is deasserted, the oscillator frequency is not doubled before being fed to the mixers.

Bit 6 of register 79, group 4 (APR 79), controls the L64734 FDOUB output pin, which enables or disables the frequency doubler on the L64733C.

The FDOUB pin is set as shown in the table below, where F_{switch} is the frequency at which the frequency doubler is enabled or disabled.

| Frequency | FDOUB APR 79[6] | TRI APR 79[2] | FDOUB Pin |
|-------------------------------|--------------------|------------------|--------------|
| 925 MHz-F _{switch} | 0 | 0 | LOW |
| F _{switch} -1680 MHz | 1 | 1 | 3-state |
| 1680–2175 MHz | 1 | 0 | HIGH |

This method of control preserves the compatibility with the L64733B, which is not affected by 3-stating the FDOUB pin.

FLCLK Filter Clock

Input

The FLCLK signal is a low amplitude, self-biased clock input. The frequency of the FLCLK signal multiplied by 16 is the baseband filter's –3 dB frequency.

IDCp, IDCn

I-Channel DC Offset Correction

Input

Connect a 0.1 μF or larger capacitor between the IDCp and IDCn signals.

INSEL RF Port Input Select

Input

When the INSEL signal is asserted, the L64733C is in normal mode. When the INSEL signal is deasserted, the L64733C is in Loop-Through mode. In this mode, the RFIN signal is looped through out to the RFOUT signal and the L64733C local oscillator is shut off.

LOBUF

Local Oscillator Buffer Select

Input

Asserting LOBUF causes the external PLL mode to be in effect, the local oscillator (LO) buffer to be enabled, and the LO signal to be sent out to the PSOUT pins according to the division ratio selected with the LODIV signal. When

LOBUF is deasserted, the internal PLL mode is in effect, and the PSOUT pins are driven from the 32/33 prescaler.

LODIV Local Oscillator Buffer Division Ratio Input

When the LODIV signal is asserted, the local oscillator (LO) buffer division ratio is set to 1; when it is deasserted, the ratio is set to 2.

MODp, MODn Prescaler Modulus

Input

The MOD differential signals form a Positive Emitter Coupled Logic (PECL) input that sets the prescaler modulus. When the MODp signal is positive with respect to the MODn signal, the prescaler modulus is set to 32 (divide by 32). When the MODn signal is positive with respect to the MODp signal, the prescaler modulus is set to 33 (divide by 33).

PLLINp, PLLINn

Phase Detector

Input

The PLLIN differential signals form the phase detector input and are connected to the L64734 PLLINp and PLLINn output signals. See the L64734 PLLINp and PLLINn descriptions in the "Synthesizer Control Interface" section.

QDCp, QDCn Q-Channel DC Offset Correction

Input

Connect a 0.1 μF or larger capacitor between the QDCp and QDCn signals.

Charge Pump Signals

The following signals are outputs from the L64733C charge pump.

CP Charge Pump Output

Connect the CP signal as shown in Figure 7, on page 23.

FB Feedback

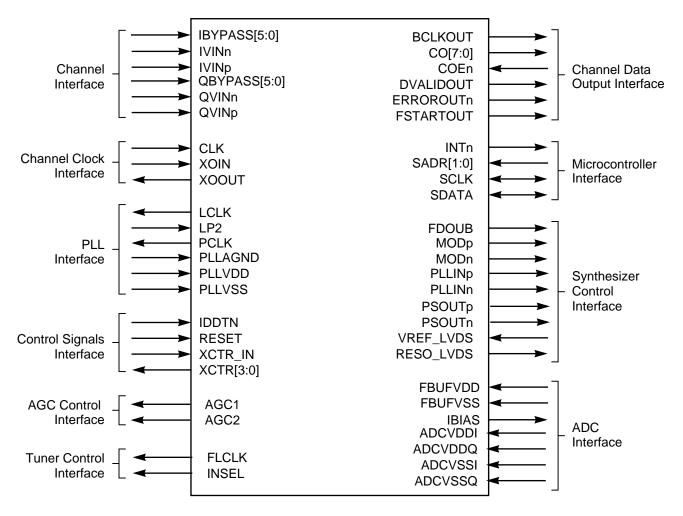
Charge Pump Transistor Drive Output

Connect the FB signal as shown in Figure 7, on page 23.

L64734 Signal Descriptions

This section describes the L64734 signals. Figure 6 shows the interface diagram of the L64734.

Figure 6 L64734 Interface Diagram



As shown in Figure 6, the L64734 has the following major interfaces:

- Channel
- Channel Clock
- PLL
- Control Signals
- ADC
- AGC Control
- Channel Data Output
- Microcontroller
- Synthesizer Control
- Tuner Control

The following signal descriptions are listed according to the major interface groups.

Channel Interface

The Channel Interface is the input path to the L64734 satellite receiver. The two signals IVIN and QVIN are the I and Q streams from the satellite tuner circuit. The CLK signal strobes in the data signals.

IBYPASS[5:0] I Channel Data

Input

The IBYPASS[5:0] signals form the digital received I channel data input bus, which supplies the I Stream to the L64734 when the ADC is bypassed. The setting of particular register bits in the L64734 controls the bypass.

IVINp, IVINn I Channel Data

Input

The IVINp and IVINn differential signals form the analog received I channel data input bus, which supplies the I stream to the L64734.

QBYPASS[5:0]

Q Channel Data

Input

The QBYPASS[5:0] signals form the digital received Q channel data input bus, which supplies the Q Stream to the L64734 when the ADC is bypassed. The setting of particular register bits in the L64734 controls the bypass.

QVINp, QVINn

Q Channel Data

Input

The QVINp and QVINn differential signals form the analog received Q channel data input bus, which supplies the Q stream to the L64734.

Channel Clock Interface

The Channel Clock Interface consists of the clock and crystal oscillator signals.

CLK IVIN/QVIN Input Clock

Input

CLK is a positive, edge-triggered clock that strobes input data to the L64734.

XOIN Crystal Oscillator In Input

The XOIN pin provides a crystal oscillator or external reference clock input. Normally, a 15 MHz crystal is

connected to the XOIN pin.

XOOUT Crystal Oscillator Out Output

The XOOUT pin is the crystal oscillator output pin.

Phase-Locked Loop (PLL) Interface

The internal PLL generates the signals to operate the ADC, Demodulator, and FEC modules.

LCLK Decimated Clock Output Output

The L64734 internal clock generation module generates the LCLK signal. LCLK is derived from CLK by dividing by the value of the CLK_DIV2 register parameter.

LP2 Input to VCO Input

The LP2 signal is the input to the internal voltage-controlled oscillator. Normally, it is connected to the output of an external RC filter circuit.

PCLK PLL Clock Output Output

The L64734 internal PLL clock synthesis module generates the PCLK signal. The reference crystal connected between the XOIN and XOOUT pins drives the PLL. The PLL clock synthesis module can be configured to generate a PCLK rate that is appropriate for all data rates.

PLLAGND PLL Analog Ground Input

PLLAGND is the analog ground pin for the PLL module and normally is connected to the system ground plane.

PLLVDD PLL Power Input

PLLVDD is the power supply pin for the PLL module and normally is connected to the system power (V_{DD}) plane.

PLLVSS PLL Ground Input

PLLVSS is the ground pin for the PLL module and normally is connected to the system ground plane.

Control Signals Interface

The Control Signals Interface controls the operation of the L64734 and is not associated with any particular interface.

IDDTN Test Input

The IDDTN pin is an LSI Logic internal test pin. Tie the IDDTN pin LOW for normal operation.

100114 pin 2011 for normal operation.

RESET Reset Input

This active-HIGH signal resets all internal data paths. Reset timing is asynchronous to the device clocks. Reset does not affect the configuration registers.

XCTR_IN Control Input Input

The XCTR_IN pin is an external input control pin. It is sensed by reading the XCTR_IN register bit.

XCTR[3] Control Output/Sync Status Flag Output

The XCTR[3] signal indicates the synchronization status for one of three synchronization modules in the L64734 or the XCTR[3] field in Group 4, APR 55. The three modules are the Viterbi Decoder, Reed-Solomon Deinterleaver (DI/RS), and Descrambler. For each of the three synchronization outputs, the asserted XCTR[3] signal indicates that synchronization is achieved for the sync module chosen using the SSS[1:0] register bits. When deasserted, the signal indicates an

out-of-synchronization condition.

XCTR[2:0] Output Control Output

The XCTR[2:0] pins are external output control pins. They are set by programming particular register bits. XCTR[2] is mapped to CPG1 and XCTR[0] is multiplexed with CPG2 when used with the L64733C Tuner IC. When the on-chip serializer generates a serial 2- or 3-wire protocol on the XCTR[2:0] pins, the mapping is XCTR[2] = EN, XCTR[1] = SCL, and XCTR[0] = SDA.

Analog-to-Digital Converter (ADC) Interface

The ADC module converts the incoming IVIN and QVIN signals into an internal 6-bit digital representation for processing. The following pins support the ADC module.

ADCVDDI/Q ADC Power Input

ADCVDDI/Q are the analog power supply pins for the ADC module and normally are connected to the system

power (V_{DD}) plane.

ADCVSSI/Q ADC Analog Ground Input

ADCVSSI/Q are the analog ground pins for the ADC module and normally are connected to the system

ground plane.

FBUFVDD Analog Supply Input

FBUFVDD is the analog supply pin for the on-chip reference voltage generator. This pin normally is connected to the system power (V_{DD}) plane.

FBUFVSS Analog Ground Input

FBUFVSS is the analog ground pin for the on-chip reference voltage generator. This pin normally is connected to the system ground (V_{SS}) plane.

IBIAS ADC Bias Current Output

This is the bias current for the ADC module. Connect this output to a 39 k Ω resistor, and connect the other side of

the resistor to ground.

AGC Control Interface

The AGC Control Interface contains signals used for power control.

AGC1, AGC2 Power Control

Output

The AGC1 and AGC2 signals are the positive $\Sigma\Delta$ modulated output used for power control. These signals can each drive an external passive RC filter that feeds a gain control stage for dual-stage AGC. For a single stage AGC, AGC1 can be used, and has the same functionality as the PWRP pin on the L64724.

Channel Data Output Interface

The Channel Data Output Interface is the output path from the L64734. It typically is connected to the input of the transport demultiplexer in a set-top decoder application.

BCLKOUT Byte Clock Out

Output

The BCLKOUT output signal is a strobe that indicates valid data bytes on the CO[7:0] bus when the L64734 is in Parallel Channel Output mode. The BCLKOUT signal cycles once every valid output data byte and is used by the transport demultiplexer to latch output data from the L64734 at the BCLKOUT rate. The BCLKOUT signal must be disregarded in Serial Channel Output mode.

CO[7:0] Channel Data Out

Output

The CO[7:0] signals form the decoded output data port. When the OF bit is 1 (Group 4, APR17), the L64734 operates in the Parallel Channel Output mode. In this mode, the L64734 outputs the channel data as 8-bit wide parallel data on the CO[7:0] signals. In Serial Channel Output mode (OF = 0), the L64734 outputs the channel data as serial data on CO[0]. The data is latched on each bit clock cycle. The chronological ordering in Serial Channel output mode is MSB oldest, LSB newest.

COEn Channel Output Enable

Input

When asserted, the COEn signal enables the ERROROUTn, CO[7:0], DVALIDOUT, BCLKOUT, and FSTARTOUT signals. Operation of the receiver continues regardless of the state of the COEn signal.

DVALIDOUT Valid

Valid Data Out

Output

The DVALIDOUT signal indicates that the CO[7:0] signals contain the corrected channel data. New data is valid on the CO[7:0] signals when the DVALIDOUT signal is asserted. DVALIDOUT is not asserted during the propagated check and GAP bytes. The DVALIDOUT signal is deasserted after the FEC_RST register bit (Group 4, APR 55) is set to one.

ERROROUTn Error Detection Flag

Output

The L64734 asserts the ERROROUTn signal at the beginning of each frame that contains an uncorrectable error, and deasserts it at the end of the frame if the error condition is removed. The ERROROUTn signal is aligned with the output data stream and is asserted after the FEC_RST register bit is set.

FSTARTOUT Frame Start Output

Output

The L64734 asserts the FSTARTOUT signal during the first bit of every frame with valid data in Serial Channel Output mode and during the first byte in Parallel Channel Output mode. FSTARTOUT is valid only when the DVALIDOUT signal is asserted. The FSTARTOUT signal is deasserted after the FEC_RST register bit is set.

Microcontroller Interface

The Microcontroller Interface connects the L64734 to an external microcontroller.

INTn Interrupt Output

The L64734 asserts INTn when an internal unmasked interrupt flag is set. The INTn signal remains asserted during the interrupt condition, and the interrupt flag is not

masked.

SADR[1:0] Serial Address Input

The SADR[1:0] signals are the two programmable bits of

the serial address for the L64734.

SCLK Serial Clock Bidirectional

SCLK is the serial clock pin for a two-wire serial protocol.

SDATA Serial Data Bidirectional

SDATA is the serial data pin for a two-wire serial protocol.

Synthesizer Control Interface

The Synthesizer Control Interface allows the L64734 to control the L64733C frequency synthesizer.

FDOUB Frequency Doubler Output, 3-State

Bit 6 of register Group 4, APR 79 controls the L64734

FDOUB output pin, which enables or disables the

frequency doubler on the L64733C.

The FDOUB pin is set as shown below; F_{switch} is the frequency that disables or enables the frequency doubler.

| Frequency | FDOUB APR 79[6] | TRI APR 79[2] | FDOUB Pin |
|-------------------------------|--------------------|------------------|--------------|
| 925 MHz-F _{switch} | 0 | 0 | LOW |
| F _{switch} -1680 MHz | 1 | 1 | 3-state |
| 1680–2175 MHz | 1 | 0 | HIGH |

MODp, MODn Modulus Selector

Output

The MODp and MODn signals are low-voltage differential signals from the L64734 of modulus selector programmable counter (A). PSOUT clocks these signals. When the MODp signal is positive with respect to the MODn signal, divide-by-32 is selected at the dual modulus prescaler on the L64733C Tuner IC. When MODp is negative with respect to MODn, divide-by-33 is selected. The counter A can be programmed to count down from a particular value by register bit programming.

PLLINp, PLLINn

PLL Differential Counter M

Output

The PLLINp and PLLINn signals are low-voltage differential signals from the L64734 programmable synthesizer counter (M). PSOUT clocks these signals. PLLINp is positive with respect to PLLINn for one PSOUT cycle. The repetition rate is 0.5 MHz for a 4 MHz reference crystal. The counter M can be programmed to count down from a particular value by register bit programming.

PSOUTp, PSOUTn

Prescaler Output

Output

The PSOUTp and PSOUTn signals are differential signals to the L64734 from the L64733C. The programmable counters on the L64734 are clocked on the rising edge of the PSOUT signal.

In the external PLL mode (LOBUF = HIGH), these signals come from the LO buffer, for which the LODIV signal sets the divider ratio.

RESO LVDS LVDS Buffers Precision Resistor

Output

The RESO_LVDS output must be connected to a resistor (6.8 k Ω , which controls the swing of the LVDSOUT

buffers used to drive the differential signals MODp, MODn, and PLLINp, PLLINn. Connect the other side of the resistor to ground.

VREF_LVDS LVDS Buffers Reference Voltage

Input

The VREF_LVDS input is a 1.2 V \pm 10% voltage level that controls the common mode voltage of the LVDSOUT buffers used to drive the differential signals MODp, MODn, and PLLINp, PLLINn.

Tuner Control Interface

The Tuner Control Interface contains signals that control the L64733C Tuner IC.

FLCLK Filter Control Clock Output

This is the output of a programmable integer value divider clocked by PCLK (the demodulator sampling clock). The division ratio can be programmed with register bits. The FLCLK frequency multiplied by 16 is the 3 dB cutoff of the programmable low pass filters on the L64733C.

INSEL RF Input Select

Output

When INSEL is asserted, the L64733C tuner selects the normal mode. When INSEL is deasserted, the L64733C selects the Loop-Through mode.

Typical Operating Circuit

Figure 7 is a diagram of a typical operating circuit for the chipset, implemented with the L64733C-48 (48-pin package), including external components. Not all external components are shown. See the *L64733/34 Evaluation Board User's Guide* for complete schematic details.

FSTARTOUT ERROROUTn SADR[188 SADR[0]> VDD PLLAGND PLLVDD PCLK VSS VSS **PLLVSS** LCLK VDD CO[0] VSS VDD CO[4] CO[5] CO[6] CO[7] VDD CO[1] CO[2] CO[3] BCLKOUT XOOUT 81 82 83 84 85 86 87 DVALIDOUT VDD VSS vss CLK SDATA VDD SCLK QBYPASS[0 INTn RESET QBYPASS[7 L64734 VDD VSS VDD **PSOUTn PSOUT**p VDD vss PLLINn 96 97 98 99 100 QBYPASS[4 PLLINp LAND TO THE TOP THE TO RESO_LVD 1 VD QZ 2 VSS 4 ADCVDDI ADCVDDQ **FBUFVDD** TO FBUFVSS QBYPASS[5 ADCVSSI XCTR[3] FDOUB FLCLK IBIAS NIN N AGC2 AGC1 1. The ground connections for the L64733C are provided via a metal plate under the IC, rather than by direct connection of the ground pins to the PCB. 2. Not all external components are shown. Refer to the L64733/34 Evaluation Board AGC Filter Varactors (2) Stripline Inductors (2) PLLIND MODP ЮПТР IOUTn аоитр MODn LODIV 22 QOUTn FDOUB PLLINn INSEL **PSOUT**p AGC2 **PSOUTn** 0.01 µF AGC1 VCC GND¹ CPG2 GND¹ XTLOUT VCC TANKn CPG1 VRLO RFOUT TANKp Guide for complete details. GND¹ VCC 6.8 kΩ LOBUF GND¹ IDCp FΒ GNDSUB1 1 kΩ 10 kΩ RFINn RFIND GND¹ ΥTZ XTLp GND 100 pF CFLT VCC **≱**22 kΩ 22 nF BC847 0.2 μF 180 pF = User's (100 pF∏ 100 pF 100 pF 100 pF ⊕ 5 MHz 47 pF Vcc Notes: 75Ω

L64733C/L64734 Tuner and Satellite Receiver Chipset

Typical Operating Circuit

Figure 7

Specifications

This section contains the electrical, timing, and mechanical specifications for the L64733C/734 chipset.

L64733C Electrical Specifications

Table 1 lists the absolute maximum values. Exceeding the values listed can cause damage to the L64733C. Table 2 gives the recommended operating supply voltage and temperature. Table 3 gives the DC characteristics; Table 4 gives the AC characteristics; and Table 5 and Table 6 summarize the pins for the 48- and 44-pin packages, respectively.

Table 1 L64733C Absolute Maximum Rating (Referenced to V_{SS})

| Symbol | Parameter | Limits ¹ | Units |
|-----------------|---|---------------------|-------|
| V _{CC} | DC supply voltage | -0.5 to +7.0 | V |
| _ | Continuous power dissipation up to +70 °C | 1.8 | W |
| _ | Derating above +70 °C | 27 | mW/°C |
| _ | Operating temperature | 0 to +70 | °C |
| _ | Junction temperature | +150 | °C |
| _ | Storage Temperature | -65 to +165 | °C |
| _ | Lead temperature (soldering 10 sec) | +300 | °C |

Note that the ratings in this table are those beyond which permanent device damage is likely to occur. Do not use these values as the limits for normal device operation.

Table 2 Recommended Operating Conditions

| Symbol | Parameter | Limits ¹ | Units |
|----------------|--|---------------------|-------|
| V_{DD} | DC Supply Voltage | 5 ± 5% | ٧ |
| T _A | Operating Ambient Temperature Range (Commercial) | 70 | °C |

For normal device operation, adhere to the limits in this table. Sustained operation of a device at conditions exceeding these values, even if they are within the absolute maximum rating limits, can result in permanent device damage or impaired device reliability. Device functionality to stated DC and AC limits is not guaranteed if recommended operating conditions are exceeded.

Table 3 DC Characteristics of the L64733C

| Parameter | Condition | Min | Тур | Max | Units |
|---|---|------|------|------|-------|
| Power Supply | | | 1 | | 1 |
| Power Supply Voltage | All DC specs met | 4.75 | 5.0 | 5.25 | V |
| Power Supply Current | | _ | 195 | 275 | mA |
| Digital Control Inputs - CPG1, CPG2, INSEL, FDOUB, LOBUF, LODIV | | | | | |
| Input Logic Level High | | 2.4 | _ | _ | V |
| Input Logic Level Low | | 0 | _ | 0.5 | V |
| Input Bias Current | Pin at 2.4 V | -15 | _ | 10 | μΑ |
| Slew-Limited Digital Clock In | nputs - FLCLK | | | | 1 |
| FLCLK Input Level Low | | - | _ | 1.45 | V |
| FLCLK Input Level High | | 1.85 | _ | _ | V |
| FLCLK Input Resistance/Leakage Current | 50 kΩ series resistor between L64734 and FLCLK pin. L64734 generates normal CMOS levels | -1 | _ | 1 | μА |
| Fast Digital Clock Inputs - N | ODp, MODn, PLLINp, PLLINn | | | | |
| MODp, MODn, PLLINp, PLLINn Common Mode Input Range (VCM) | | 1.08 | 1.2 | 1.32 | V |
| MODp, MODn, PLLINp, PLLINn Input Voltage Low | MODp, MODn, or PLLINp, PLLINn differential swing around VCM. Need external 100- Ω termination. | _ | _ | -100 | mV |
| MODp, MODn, PLLINp, PLLINn Input Voltage High | MODp, MODn, or PLLINp, PLLINn differential swing around VCM. Need external 100- Ω termination | 100 | _ | - | mV |
| MODp, MODn, PLLINp, PLLINn Input Current | MODp, MODn, PLLINp, PLLINn | -5 | _ | +5 | μА |
| Digital Clock Outputs - PSO | UTp, PSOUTn | | | | 1 |
| PSOUTp, PSOUTn Common Mode Output Range (VCM) | | 2.16 | 2.4 | 2.64 | V |
| PSOUTp, PSOUTn Output Voltage Low | PSOUTp, PSOUTn differential swing around VCM. Driving LSI PECL Load (±10 μA), LOBUF = 0 | - | -215 | -150 | mV |
| (Sheet 1 of 3) | | | | | |

Table 3 DC Characteristics of the L64733C (Cont.)

| Parameter | Condition | Min | Тур | Max | Units |
|---|---|-------|------|-------|-------|
| PSOUTp, PSOUTn Output Voltage High | PSOUTp, PSOUTn differential swing around VCM. Driving LSI PECL Load (±10 μA), LOBUF = 0 | 150 | 215 | _ | mV |
| PSOUTp, PSOUTn Output Voltage Low | PSOUTp, PSOUTn differential swing around VCM, driving 100 Ω differential LOBUF = 1 | _ | -140 | -100 | mV |
| PSOUTp, PSOUTn Output Voltage High | PSOUTp, PSOUTn differential swing around VCM, driving 100 Ω differential. LOBUF is asserted. | 100 | 140 | _ | mV |
| Synthesizer/Local Oscillator | Buffer | 1 | | | 1 |
| Prescaler Ratio | MOD = High | 32 | _ | 32 | _ |
| | MOD = Low | 33 | _ | 33 | _ |
| LO Buffer Division Ratio | LOBUF = High, LODIV = Low | | 2 | | _ |
| | LOBUF = High, LODIV = High | 1 | | | _ |
| Reference Divider Ratio | | 8 | _ | 8 | _ |
| Charge Pump Output High Current (at FB) | CPG1, CPG2 = 0, 0 | 0.08 | 0.1 | 0.12 | mA |
| | CPG1, CPG2 = 0, 1 | 0.24 | 0.3 | 0.36 | mA |
| | CPG1, CPG2 = 1, 0 | 0.48 | 0.6 | 0.72 | mA |
| | CPG1, CPG2 = 1, 1 | 1.44 | 1.8 | 2.16 | mA |
| Charge Pump Output Low | CPG1, CPG2 = 0, 0 | -0.12 | -0.1 | -0.08 | mA |
| Current (at FB) | CPG1, CPG2 = 0, 1 | -0.36 | -0.3 | -0.24 | mA |
| | CPG1, CPG2 = 1, 0 | -0.72 | -0.6 | -0.48 | mA |
| | CPG1, CPG2 = 1, 1 | -2.16 | -1.8 | -1.44 | mA |
| Charge Pump Output Leakage Current | | -25 | _ | 25 | nA |
| Charge Pump Positive-to-Negative Current Matching | FB self-biased. | -5 | _ | 5 | % |
| Charge Pump Output Transistor Base Current Drive | | 100 | _ | - | μА |
| (Sheet 2 of 3) | | | | | · |

Table 3 DC Characteristics of the L64733C (Cont.)

| Parameter | Condition | Min | Тур | Max | Units | | |
|--|---|------|-----|------|-----------------|--|--|
| Analog Control Inputs - AGC1, AGC2 | | | | | | | |
| Input Bias Current | 1 V < Pin < 4 V | -50 | _ | 50 | μΑ | | |
| Baseband Outputs - IOUTp, | IOUTn, QOUTp, QOUTn | | | | | | |
| Output Swing | Loaded with 2 k Ω differential across IOUTp, IOUTn, and QOUTp, QOUTn | 1 | _ | _ | V _{PP} | | |
| IOUTp, IOUTn, QOUTp, QOUTn Common Mode Voltage | | 0.65 | _ | 0.85 | V | | |
| IOUTp, IOUTn, QOUTp, QOUTn DC Offset Voltage | | -50 | _ | 50 | mV | | |
| (Sheet 3 of 3) | | | 1 | | • | | |

Table 4 AC Characteristics of the L64733C

| Parameter | Condition | | Min | Тур | Max | Units |
|--|---|-----------------------------------|-------------|----------------------|-------------|-------------------|
| RF Front End | | | | | • | |
| RFIN Input Freq. Range | Meets all following AC sp | ecs | 925 | - | 2175 | MHz |
| RFIN Single-Carrier Input Power ¹ | RF level needed to produ | ice 0.59 V _{PP} | -68 | - | -25 | dBm |
| AGC1 Range | 1 V < AGC1 < 4 V | | 50 | _ | _ | dB |
| AGC2 Range | 1 V < AGC2 < 4 V | 1 V < AGC2 < 4 V | | _ | _ | dB |
| RFIN referred IP3 (front-end contributions) | AGC1 gain set for –25 dBm input level (0.59 V _{PP} output), and AGC2 set to maximum gain (V _{AGC2} = 1 V). Two signals at FLO + 32 MHz, FLO + 72 MHz | @2175 MHz @1550MHz @925 MHz | _ _ _ | 10.5 11.5 10.5 | - - - | dBm dBm dBm |
| Baseband 1 dB Compression Point | IOUTp, IOUTn, QOUTp, QOUTn have one signal within filter bandwidth | | 2 | _ | _ | V _{PP} |
| RFIN Referred IP2 | PRFIN = -25 dBm, F_{LO} = 951 MHz | | _ | 15.5 | _ | dBm |
| (Sheet 1 of 3) | • | | ' | | • | |

Table 4 AC Characteristics of the L64733C (Cont.)

| Parameter | Condition | | Min | Тур | Max | Units |
|--|--|-----------------------------------|-----|----------------------------------|-----|-----------------|
| Noise Figure | At maximum gain AGC1, AGC2, 2150 MHz | | _ | 10.8 | _ | dB |
| RFIN Return Loss | Complex "75 Ω source" subject to board, connector parasitics. | | _ | 11 | _ | dB |
| LO Leakage Power at RFIN | 950 MHz to 2150 MHz, s board layout | subject to | _ | -65 | _ | dBm |
| Second Harmonic Rejection | Due to LO-generated 2nd | d harmonic | _ | 44 | _ | dB |
| Half-Harmonic Rejection and x 1.5 Harmonic Rejection ² | Due to RFIN-generated 2 | and harmonic | - | 40 | _ | dB |
| Loop Through | | | | 1 | | |
| Gain | | @2175 MHz @1550MHz @925 MHz | _ | 2.0 1.0 0.5 | _ | dB |
| RFIN referred IP3 (when Loop-Through enabled) | At PRFIN = -25 dBm | @2175 MHz @1550MHz @925 MHz | - | 5.4 7.7 9.5 | _ | dBm |
| Noise Figure | | | _ | 12.0 | _ | dB |
| Return Loss | Subject to board and con parasitics | nector | _ | 8 | _ | dB |
| Baseband | | | | 1 | | |
| IOUTp, IOUTn, QOUTp, QOUTn Differential Output Voltage Swing | $2~\text{k}\Omega$ differential load, IOI QOUTp, QOUTn. Expect each pin to GND | | 1 | _ | _ | V _{PP} |
| IOUTp, IOUTn, QOUTp, QOUTn Output Impedance | Per side, IOUTp, IOUTn, QOUTn. To 200 MHz | QOUTp, | _ | _ | 50 | Ω |
| Baseband Highpass –3 dB Point | $0.22~\mu F$ caps connected from IDCp to IDCn, and QDCp to QDCn. | | _ | _ | 750 | Hz |
| LPF Nominal Cutoff Frequency Range | Fc is -3 dB point of filter | | 8 | _ | 33 | MHz |
| LPF Nominal Fc | | | _ | 14.5 · F _{FLCLK} + 1 | - | _ |
| (Sheet 2 of 3) | | | | , | | |

AC Characteristics of the L64733C (Cont.) Table 4

| Parameter | Condition | | Min | Тур | Max | Units |
|--|---|---------------------|-------------|-------------|-----------|--------|
| Baseband Frequency Response | Deviation from ideal 7th-order Butterworth, measure to F – 3 dB x 0.7. Include front-end tilt effects | | -0.5 | _ | 0.5 | dB |
| LPF Cutoff Frequency Accuracy | Measured -3 dB point. | @8 MHz @31.4 MHz | -5.5 -10 | _ _ | 5.5 10 | % % |
| Quadrature Gain Error | Includes effects from bas | eband filters | _ | _ | 1.2 | dB |
| Quadrature Phase Error | Measure at 125 kHz | | _ | _ | 4 | Deg |
| Synthesizer | | | | | | |
| Crystal Frequency Range | | | 4 | _ | 7.26 | MHz |
| XTLOUT Voltage Levels | Measured on 10 pF in pa 1 $M\Omega$ | arallel with | 0.75 | 1.0 | 1.5 | Vpp |
| XTLOUT DC Level | | | _ | 2.0 | _ | V |
| MODp, MODn Delay | Must assert MOD level within this time period to ensure that the next PSOUT period gives correct count. Delay is with respect to rising edge of PSOUT (previous count). | | _ | _ | 7 | nsec |
| PLLINp, PLLINn and MODp, MODn Hold Time | With respect to rising edge of PSOUT. This means that PSOUT need not continue to be asserted after MOD has given correct count. | | 0 | _ | - | nsec |
| Local Oscillator | | | | | | |
| LO Tuning Range | | | 543 | _ | 1180 | MHz |
| LO Phase Noise, Including Doubler. Subject to LC tank | 1 kHz offset. Depends or gain. | PLL loop | _ | – 55 | _ | dBc/Hz |
| implementation. | 10 kHz offset. Depends on PLL loop gain. | | _ | -75 | - | dBc/Hz |
| | 100 kHz offset | | _ | -95 | _ | dBc/Hz |
| LO Buffer Frequency Range when overdriven by external LO | FDOUB = low | | 925 | - | 2175 | MHz |
| (Sheet 3 of 3) | , | | | | ' | 1 |

^{1.} For symbol rates below 15 MS/s, the maximum input power might be subject to shifting down by roughly 10 * log(15/Rs[MS/s]) dB due to channel bandwidth reduction. 2. x 1.5 harmonic rejection for $F_{LO} = 725$ MHz.

Table 5 L64733C-48 Pin Description Summary

| Mnemonic | Description | Туре |
|----------------|---|---------------|
| AGC1 | Automatic Gain Control 1 | Input |
| AGC2 | Automatic Gain Control 2 | Input |
| CFLT | Bias Voltage Bypass | Bidirectional |
| СР | Charge Pump | Output |
| CPG[2:1] | Charge Pump Gain | Input |
| FB | Feedback Charge Pump Transistor Drive | Output |
| FDOUB | Frequency Doubler | Input |
| FLCLK | Filter Clock | Input |
| GND | Ground (seven pins total) | Input |
| IDCp | I-Channel DC Offset Correction (noninverting) | Input |
| IDCn | I-Channel DC Offset Correction (inverting) | Input |
| INSEL | RF Port Input Select | Input |
| IOUTp | I-Channel Baseband Data (noninverting) | Output |
| IOUTn | I-Channel Baseband Data (inverting) | Output |
| LOBUF | Local Oscillator Buffer Select | Input |
| LODIV | Local Oscillator Buffer Division Ratio Select | Input |
| MODp | Prescaler Modulus (noninverting) | Input |
| MODn | Prescaler Modulus (inverting) | Input |
| PLLINp | Phase Detector (noninverting) | Input |
| PLLINn | Phase Detector (inverting) | Input |
| PSOUTp | Prescaler (noninverting) | Output |
| PSOUTn | Prescaler (inverting) | Output |
| QDCp | Q-Channel DC Offset Correction (noninverting) | Input |
| (Sheet 1 of 2) | | |

Table 5 L64733C-48 Pin Description Summary (Cont.)

| Mnemonic | Description | Туре |
|----------------|--|---------------|
| QDCn | Q-Channel DC Offset Correction (inverting) | Input |
| QOUTp | Q-Channel Baseband Data (noninverting) | Output |
| QOUTn | Q-Channel Baseband Data (inverting) | Output |
| RFINp | RF Input (noninverting) | Input |
| RFINn | RF Input (inverting) | Input |
| RFOUT | RF Output (Loop-Through) | Output |
| TANKp | Oscillator Tank Port (noninverting) | Input |
| TANKn | Oscillator Tank Port (inverting) | Input |
| VCC | Power (six pins total) | Input |
| VRLO | Local Oscillator Regulator Bypass | Bidirectional |
| XTLp | Crystal Oscillator Port (noninverting) | Input |
| XTLn | Crystal Oscillator Port (inverting) | Input |
| XTLOUT | Crystal Out | Output |
| (Sheet 2 of 2) | | |

Table 6 L64733C-44 Pin Description Summary

| Mnemonic | Description | Туре |
|----------------|---|---------------|
| AGC1 | Automatic Gain Control 1 | Input |
| AGC2 | Automatic Gain Control 2 | Input |
| CFLT | Bias Voltage Bypass | Bidirectional |
| СР | Charge Pump | Output |
| CPG[2:1] | Charge Pump Gain | Input |
| FB | Feedback Charge Pump Transistor Drive | Output |
| FDOUB | Frequency Doubler | Input |
| FLCLK | Filter Clock | Input |
| GND | Ground (three pins total) | Input |
| IDCp | I-Channel DC Offset Correction (noninverting) | Input |
| IDCn | I-Channel DC Offset Correction (inverting) | Input |
| INSEL | RF Port Input Select | Input |
| IOUTp | I-Channel Baseband Data (noninverting) | Output |
| IOUTn | I-Channel Baseband Data (inverting) | Output |
| LOBUF | Local Oscillator Buffer Select | Input |
| LODIV | Local Oscillator Buffer Division Ratio Select | Input |
| MODp | Prescaler Modulus (noninverting) | Input |
| MODn | Prescaler Modulus (inverting) | Input |
| PLLINp | Phase Detector (noninverting) | Input |
| PLLINn | Phase Detector (inverting) | Input |
| PSOUTp | Prescaler (noninverting) | Output |
| PSOUTn | Prescaler (inverting) | Output |
| QDCp | Q-Channel DC Offset Correction (noninverting) | Input |
| (Sheet 1 of 2) | | |

Table 6 L64733C-44 Pin Description Summary (Cont.)

| Mnemonic | Description | Туре |
|----------------|--|---------------|
| QDCn | Q-Channel DC Offset Correction (inverting) | Input |
| QOUTp | Q-Channel Baseband Data (noninverting) | Output |
| QOUTn | Q-Channel Baseband Data (inverting) | Output |
| RFINp | RF Input (noninverting) | Input |
| RFINn | RF Input (inverting) | Input |
| RFOUT | RF Output (Loop-Through) | Output |
| TANKp | Oscillator Tank Port (noninverting) | Input |
| TANKn | Oscillator Tank Port (inverting) | Input |
| VCC | Power (six pins total) | Input |
| VRLO | Local Oscillator Regulator Bypass | Bidirectional |
| XTLp | Crystal Oscillator Port (noninverting) | Input |
| XTLn | Crystal Oscillator Port (inverting) | Input |
| XTLOUT | Crystal Out | Output |
| (Sheet 2 of 2) | | |

L64734 Electrical Specifications

This section contains the electrical parameters for the L64734. Table 7 lists the absolute maximum values. Exceeding the values listed can cause damage to the L64734. Table 8 gives the recommended operating supply voltage and temperature conditions. Table 9 shows the pin capacitance, Table 10 gives the DC characteristics, and Table 11 summarizes the pins.

Table 7 L64734 Absolute Maximum Rating (Referenced to V_{SS})

| Symbol | Parameter | Limits ¹ | Units |
|------------------|-------------------------------------|-------------------------------|-------|
| V _{DD} | DC Supply Voltage | -0.3 to + 3.9 | ٧ |
| V _{IN} | LVTTL Input Voltage | -1.0 to V _{DD} + 0.3 | V |
| V _{IN} | 5 V Compatible Input Voltage | -1.0 to 6.5 | V |
| I _{IN} | DC Input Current | ±10 | mA |
| T _{STG} | Storage Temperature Range (Plastic) | -40 to +125 | °C |

^{1.} Note that the ratings in this table are those beyond which permanent device damage is likely to occur. Do not use these values as the limits for normal device operation.

Table 8 L64734 Recommended Operating Conditions

| Symbol | Parameter | Limits ¹ | Units |
|----------------|--|---------------------|---------|
| V_{DD} | DC Supply Voltage | +3.14 to 3.47 | V |
| T _A | Operating Ambient Temperature Range (Commercial) | 0 to +70 | °C |
| Tj | Junction Temperature | +125 | °C |
| Θ_{jc} | Junction to Case Thermal Resistance ² | 7 | °C/watt |

For normal device operation, adhere to the limits in this table. Sustained operation of a device at conditions exceeding these values, even if they are within the absolute maximum rating limits, can result in permanent device damage or impaired device reliability. Device functionality to stated DC and AC limits is not guaranteed if recommended operating conditions are exceeded.

Table 9 L64734 Capacitance

| Symbol | Symbol Parameter ¹ | | Units |
|------------------|-------------------------------|---|-------|
| C _{IN} | Input Capacitance | 5 | pF |
| C _{OUT} | Output Capacitance | 5 | pF |

^{1.} Measurement conditions are V_{IN} = 3.3 V, T_A = 25 °C, and clock frequency = 1 MHz.

^{2.} The junction to case thermal resistance is valid for measurements in an isothermal environment including the board and package.

Table 10 DC Characteristics of the L64734

| Symbol | Parameter | Condition ¹ | Min | Тур | Max | Units |
|----------------------|--------------------------------------|---|----------------------------|------|--------------------------|-------|
| V _{DD} | Supply Voltage | | 3.0 | 3.3 | 3.6 | V |
| V _{IL} | Input Voltage LOW | | V _{SS} - 0.5 | _ | 0.8 | V |
| V _{IH} | Input Voltage HIGH | LVTTL Com/Ind/Mil Temp Range | 2.0 | _ | V _{DD} + 0.3 | V |
| | | 5 V compatible | 2.0 | _ | 5.5 | V |
| V _T | Switching Threshold | | _ | 1.4 | 2.0 | V |
| I _{IL} | Input Current Leakage | $V_{DD} = Max,$ $V_{IN} = V_{DD} \text{ or } V_{SS}$ | -10 | ±1 | 10 | μА |
| I _{IPU} | Input Current Leakage with Pull-up | V _{IN} = V _{SS} | -62 | -215 | -384 | μА |
| I _{IPD} | Input Current Leakage with Pull-down | $V_{IN} = V_{DD}$ | -62 | -215 | -384 | μА |
| V _{OH} | Output Voltage HIGH | I _{OH} = -1.0, -2.0, -4.0, -6.0, -8.0, -12.0 mA | 2.4 | _ | V _{DD} | V |
| V _{OL} | Output Voltage LOW | I _{OH} = 1.0, 2.0, 4.0, 6.0, 8.0, 12.0 mA | _ | 0.2 | 0.4 | V |
| l _{OZ} | 3-State Output Leakage Current | $V_{DD} = Max,$ $V_{OUT} = V_{SS} \text{ or } 3.5 \text{ V}$ | -10 | ±1 | 10 | μА |
| I _{DD} | Quiescent Supply Current | $V_{IN} = V_{DD}$ or V_{SS} | - 2 | | 2 | mA |
| I _{CC} | Dynamic Supply Current | f = MHz, V _{DD} = Max | _ | 290 | _ | mA |
| V_{CM} | Midpoint of PSOUTp, PSOUTn inputs | | _ | 2.4 | _ | V |
| V _{IH_PECL} | Input Voltage High Level (DC) | PSOUTp - PSOUTn = 50 mV | V _{CM} + 50 mV | _ | _ | V |
| (Sheet 1 of | 2) | | 1 | 1 | | 1 |

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Table 10 DC Characteristics of the L64734 (Cont.)

| Symbol | Parameter | Condition ¹ | Min | Тур | Max | Units |
|------------------------|-----------------------------------|--|-------|-------|----------------------------|-------|
| V _{IL_PECL} | Input Voltage Low Level (DC) | PSOUTp - PSOUTn = 50 mV | _ | _ | V _{CM} – 50 mV | V |
| I _{IL_PECL} | Input Low Current | V _{IN} = V _{SS} | -10 | _ | _ | μА |
| I _{IH_PECL} | Input High Current | $V_{IN} = V_{DD}$ | _ | _ | +10 | μΑ |
| V _{RESO_LVDS} | Output Voltage on pin RESO_LVDS | | _ | 1.2 | _ | V |
| V _{OH_LVDS} | Output Voltage High Level (DC) | On PLLINp/PLLINn, MODp/MODn signals | 1.253 | 1.373 | 1.437 | V |
| V _{OL_LVDS} | Output Voltage Low Level (DC) | On PLLINp/PLLINn, MODp/MODn signals | 1.030 | 1.032 | 1.059 | V |
| (Sheet 2 of 2) | | | | | | |

^{1.} Specified at V_{DD} = 3.3 V \pm 5% at ambient temperature over the specified range.

Table 11 L64734 Pin Description Summary

| Mnemonic | Description | Туре |
|----------------|-----------------------|---------|
| ADCVDDI/Q | ADC Power | Input |
| ADCVSSI/Q | ADC Analog Ground | Input |
| AGC1, AGC2 | Power Control | Outputs |
| BCLKOUT | Byte Clock Out | Output |
| CLK | IVIN/QVIN Input Clock | Input |
| CO[7:0] | Channel Data Out | Output |
| COEn | Channel Output Enable | Input |
| DVALIDOUT | Valid Data Out | Output |
| ERROROUTn | Error Detection Flag | Output |
| FBUFVDD | Analog Supply | Input |
| FBUFVSS | Analog Ground | Input |
| (Sheet 1 of 3) | | |

Table 11 L64734 Pin Description Summary (Cont.)

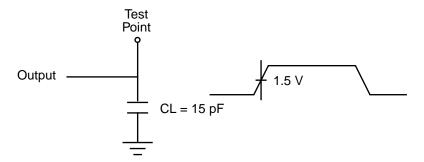
| Mnemonic | Description | Туре |
|----------------|---------------------------------|-----------------|
| FDOUB | Frequency Doubler | Output, 3-State |
| FLCLK | Filter Control Clock | Output |
| FSTARTOUT | Frame Start Output | Output |
| IBIAS | ADC Bias Current | Output |
| IBYPASS[5:0] | I Channel Data (ADC bypassed) | Inputs |
| IDDTN | Test | Input |
| INSEL | RF Input Select | Output |
| INTn | Interrupt | Output |
| IVINn, IVINp | I Channel Data | Input |
| LCLK | Decimated Clock Output | Output |
| LP2 | Input to VCO | Input |
| MODp, MODn | Modulus Selector | Outputs |
| PCLK | PLL Clock Output | Output |
| PLLAGND | PLL Analog Ground | Input |
| PLLINn, PLLINp | PLL Differential Counter M | Outputs |
| PLLVDD | PLL Power | Input |
| PLLVSS | PLL Ground | Input |
| PSOUTp, PSOUTn | Prescaler Output | Outputs |
| QBYPASS[5:0] | Q Channel Data (ADC bypassed) | Input |
| QVINn, QVINp | Q Channel Data | Input |
| RESET | Reset | Input |
| RESO_LVDS | LVDS Buffers Precision Resistor | Output |
| SADR[1:0] | Serial Address | Input |
| SCLK | Serial Clock | Bidirectional |
| (Sheet 2 of 3) | | |

Table 11 L64734 Pin Description Summary (Cont.)

| Mnemonic | Description | Туре |
|----------------|---------------------------------|---------------|
| SDATA | Serial Data | Bidirectional |
| VREF_LVDS | LVDS Buffers Reference Voltage | Input |
| XCTR_IN | Control Input | Input |
| XCTR[3:0] | Control Output/Sync Status Flag | Output |
| XOIN | Crystal Oscillator In | Input |
| XOOUT | Crystal Oscillator Out | Output |
| (Sheet 3 of 3) | | |

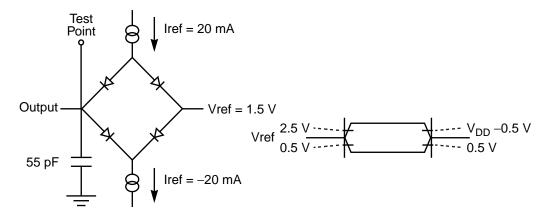
This section includes AC timing information for the L64734. During AC testing, HIGH inputs are driven to 3.0 V and LOW inputs are driven to 0 V. For transitions between HIGH, LOW, and invalid states, timing measurements are made at 1.5 V, as shown in Figure 8.

Figure 8 AC Test Load and Waveform for Standard Outputs



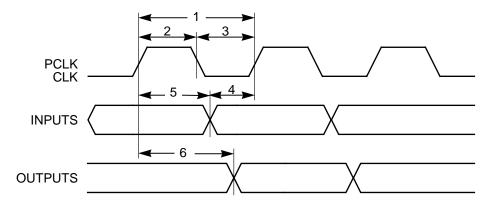
For 3-state outputs, timing measurements are made from the point at which the output turns ON or OFF. An output is ON when its voltage is greater than 2.5 V or less than 0.5 V. An output is OFF when its voltage is less than $V_{DD}-0.5$ V or greater than 0.5 V, as shown in Figure 9.

Figure 9 AC Test Load and Waveforms for 3-State Outputs



Synchronous timing is shown in Figure 10. Synchronous inputs must have a setup and hold relationship with respect to the clock signal that samples them. Synchronous outputs have a delay from the clock edge that asserts them.

Figure 10 L64734 Synchronous AC Timing



The reset pulse requirements are shown in Figure 11.

Figure 11 L64734 RESET Timing Diagram

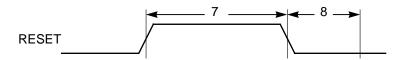


Figure 12 shows the relationship of the L64734 3-state signals to the COEn signal.

Figure 12 L64734 Bus 3-State Delay Timing

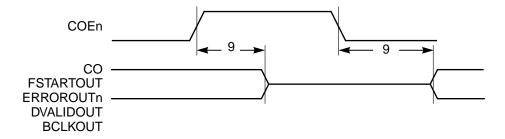
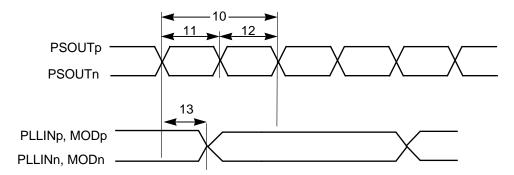


Figure 13 shows the relationship of the L64733C PSOUTp and PSOUTn prescaler signals to the signals fed back to the L64733C from the L64734 to control the synthesizer.

Figure 13 L64734 Synchronous AC Timing - Synthesizer Control



The numbers in the first column of Table 12 refer to the timing parameters shown in the preceding figures. All parameters in the timing tables apply for $T_A = 0$ °C to 70 °C and a capacitive load of 15 pF.

Table 12 L64734 AC Timing Parameters

| | | | 90 | MHz | |
|-----------|-----------------------|--|------|-------------------|----------------|
| Parameter | | Description | Min | Max | Units |
| 1 | t _{CYCLE} | Clock Cycle for PCLK | 11.1 | 33.3 ¹ | ns |
| 2 | t _{PWH} | Clock Pulse Width HIGH | 6 | _ | ns |
| 3 | t _{PWL} | Clock Pulse Width LOW | 5 | _ | ns |
| 4 | t _S | Input Setup Time to CLK | 4 | _ | ns |
| 5 | t _H | Input Hold to CLK | 4 | _ | ns |
| 6 | t _{ODS} | Output Delay from PCLK, serial mode | 3 | 8 | ns |
| 6 | t _{ODP} | Output Delay from BCLKOUT, parallel mode | 3 | - | PCLK cycles |
| 7 | t _{RWH} | Reset Pulse Width HIGH | 3 | _ | CLK cycles |
| 8 | t _{WK} | Wake-Up Time | 280 | _ | CLK cycles |
| 9 | T _{DLY} | Delay from COEn | _ | 6 | ns |
| 10 | t _{CYCLE_PS} | Clock Cycle for PSOUTp, PSOUTn clock | 14 | 35 | ns |
| 11 | t _{PWH_PS} | PSOUT Clock Pulse Width HIGH | 6 | _ | ns |
| 12 | t _{PWL_PS} | PSOUT Clock Pulse Width LOW | 6 | _ | ns |

^{1.} Minimum Fs (sampling clock = 30 MHz).

L64733C/734 Chipset Ordering Information

The L64733C-48 is available in a 48-pin TQFP package, the L64733C-44 is available in a 44-pin MLF2 package, and the L64734 is available in a 100-pin PQFP package. They are ordered as a set. Table 13 gives ordering information for the chipset.

Table 13 L64733C/734 Chipset Ordering Information

| Order Number | Package Type | Operating Range |
|----------------------------------|--|-----------------|
| Kit 733x 734y x = 733 version | 48-pin TQFP (L64733C-48) 44-pin MLF2 (L64733C-44) | Commercial |
| y = 734 version | 100-pin PQFP (L64734) | |

The tables and figures that follow provide pinouts and mechanical drawings for each package in the chipset.

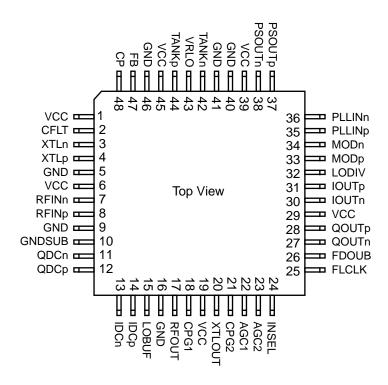
L64733C-48 Pinout and Packaging Information

The following subsections provide pinout and packaging information for the 48-pin L64733C chip.

L64733C-48 Pinouts

Figure 14 gives the pinout for the 48-pin TQFP L64733C-48 package.

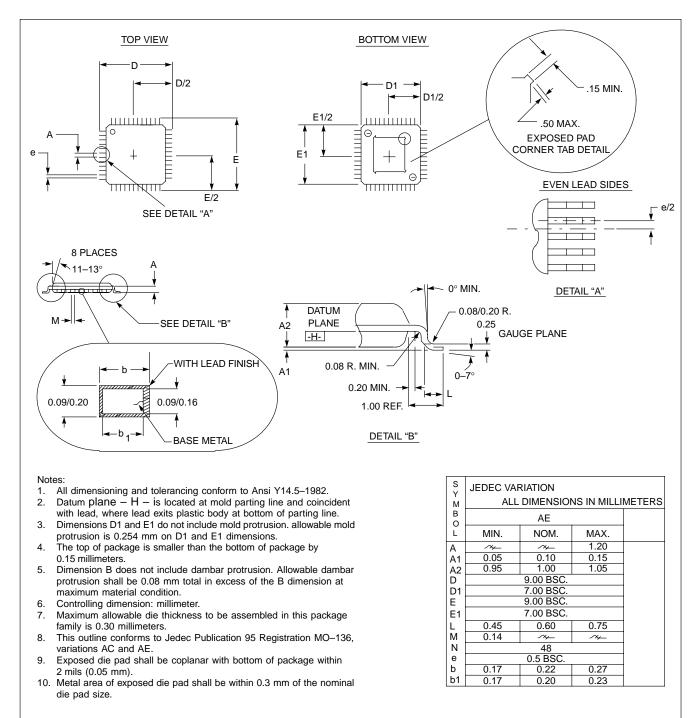
Figure 14 L64733C 48-Pin TQFP Pinout



L64733C-48 Mechanical Drawing

Figure 15 is a mechanical drawing for the 48-pin TQFP L64733C-48 package.

Figure 15 L64733C-48 48-pin TQFP Mechanical Drawing



L64733C-44 Pinout and Packaging Information

The following subsections provide pinout and packaging information for the 44-pin L64733C chip.

PLLINp

MODn

MODp

IOUTp

IOUTn

QOUTp

QOUTn

VCC

FDIV

□ FLCLK

L6433C-44 Pinout

XTALp □

CFLT C

VCC -

NC =

VCC =

RFINn -

RFINp =

NC

QDCn □

QDCP =

Figure 16 gives the pinout for the 44-pin QFN L64733-44 package.

L6473

44 Pin QFN

Top View

CPG1/VCO0 VCC XTALOUT

CPG2/VC01

Figure 16 L64733 44-Pin QFN Pinout

L64733C-44 Mechanical Drawings

Figure 17 is a mechanical drawing for the 44-pin QFN L64733-44 package.

Figure 17 L64733C-44 44-pin QFN Mechanical Drawing

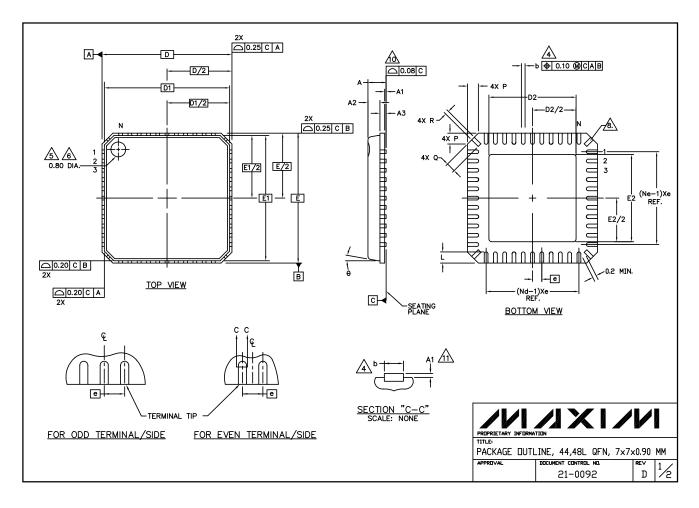


Figure 17 L64753-44 44-pin QFN Mechanical Drawing (Cont.)

NOTES:

- 1. DIE THICKNESS ALLOWABLE IS 0.305mm MAXIMUM(.012 INCHES MAXIMUM)
- 2. DIMENSIONING & TOLERANCES CONFORM TO ASME Y14.5M. 1994.

 3. N IS THE NUMBER OF TERMINALS.

 Nd IS THE NUMBER OF TERMINALS IN X-DIRECTION &

 Ne IS THE NUMBER OF TERMINALS IN Y-DIRECTION.
- ADIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.20 AND 0.25mm FROM TERMINAL TIP.
- ATTICLE OF THE PIN #1 IDENTIFIER MUST EXIST ON THE TOP SURFACE OF THE PACKAGE BY USING INDENTATION MARK OR OTHER FEATURE OF PACKAGE BODY.
- 6 EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL.
- 7. ALL DIMENSIONS ARE IN MILLIMETERS.
- 1/0. THE SHAPE SHOWN ON FOUR CORNERS ARE NOT ACTUAL I/O.
- 9. PACKAGE WARPAGE MAX 0.08mm.
- APPLIED FOR EXPOSED PAD AND TERMINALS.
 EXCLUDE EMBEDDING PART OF EXPOSED PAD FROM MEASURING.
- APPLIED ONLY FOR TERMINALS.
- 12. MEETS JEDEC MO220.

| S | DITCH | VARIAT | ION C | | S _Y | DITCH | VARIA1 | ION D | |
|------------|------------------------------------|------------|--------------|------------------|----------------|----------|------------|------------|-----|
| M | THE VARIATION C | | | N _O | M | FITCH | VAINA | ION D | No_ |
| <u>ا</u> و | MIN. | NOM. | MAX. | NO _{TE} | ٩ | MIN. | NOM. | MAX. | TE. |
| e | | 0.50 BSC | | | e | | 0.50 BSC | | |
| N | 44 | | | 3 | N | | 48 | | 3 |
| Nd | 11 | | | 3 | ρZ | 12 | | | 3 |
| Ne | 11 | | | 3 | Ne | 12 | | | 3 |
| L | 0.50 | 0.60 | 0.75 | | Г | 0.30 | 0.40 | 0.45 | |
| Ь | 0.18 | 0.23 | 0.30 | 4 | Ф | 0.18 | 0.23 | 0.30 | 4 |
| Q | 0.30 | 0.40 | 0.65 | | Ø | 0.00 | 0.20 | 0.45 | |
| D2 | D2SEE EXPOSED PAD VARIATION: A,B,D | | | | D2 | SEE EXPO | SED PAD VA | RIATION: C | |
| E2 | SEE EXPOSE | D PAD VARI | ATION: A,B,D | | E2 | SEE EXPO | SED PAD VA | RIATION: C | |

| S | COMMON DIMENSIONS | | | | | | |
|------|----------------------|----------------|------|----|--|--|--|
| MB O | DI | N _O | | | | | |
| ٦ | MIN. | NOM. | MAX. | Ťε | | | |
| Α | _ | 0.90 | 1.00 | | | | |
| A1 | 0.00 | 0.01 | 0.05 | 11 | | | |
| Α2 | ı | 0.65 | 0.80 | | | | |
| Α3 | | 0.20 REF. | | | | | |
| D | | 7.00 BSC | | | | | |
| ū | | 6.75 BSC | | | | | |
| Е | | 7.00 BSC | | | | | |
| E1 | | 6.75 BSC | | | | | |
| Φ | | | | | | | |
| Ρ | 0.24 | 0.42 | 0.60 | | | | |
| R | 0.13 | 0.17 | 0.23 | | | | |
| | | | | | | | |

| SYMBOLS | | | D2 | | | E2 | | NOTE |
|-------------|---|------|------|------|------|------|------|------|
| | | MIN | NOM | MAX | MIN | NOM | MAX | |
| EXPOSED PAD | Α | 4.55 | 4.70 | 4.85 | 4.55 | 4.70 | 4.85 | |
| VARIATIONS | В | 3.15 | 3.30 | 3.45 | 3.15 | 3.30 | 3.45 | |
| | С | 4.95 | 5.10 | 5.25 | 4.95 | 5.10 | 5.25 | |
| | Δ | 3.65 | 3.80 | 3.95 | 3.65 | 3.80 | 3.95 | |

EXAMPLE: WE CAN CALL VARIATION "CA" FOR 44 TERMINAL QFN WITH 4.70x4.70 mm NOMINAL EXPOSED PAD DIMENSION. THE FORMER ONE IN VARIATION IS FOR PITCH VARIATION AND THE LATTER ONE IS FOR EXPOSED PAD VARIATION.

| PROPRIETARY INFORMAT | | | |
|----------------------|------------------------|-------|----|
| TITLE | | | |
| PACKAGE DUTL | .INE, 44,48L QFN, 7×7> | <0.90 | MM |
| APPROVAL. | DOCUMENT CONTROL NO. | REV | 2/ |
| | 21-0092 | D | 2 |

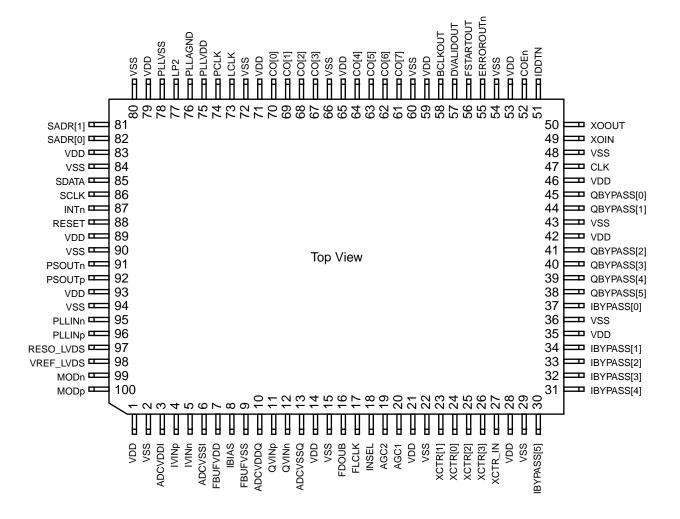
L64734 Pinout and Packaging Information

The following subsections provide pinout and packaging information for the L64734.

L64734 Pinouts

Figure 18 gives the pinout for the 100-pin PQFP L64734 package.

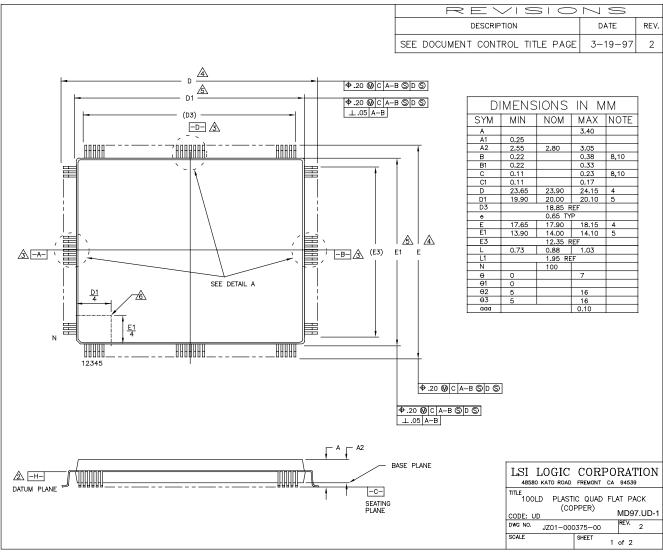
Figure 18 L64734 100-Pin PQFP Pinout



L64734 Mechanical Drawings

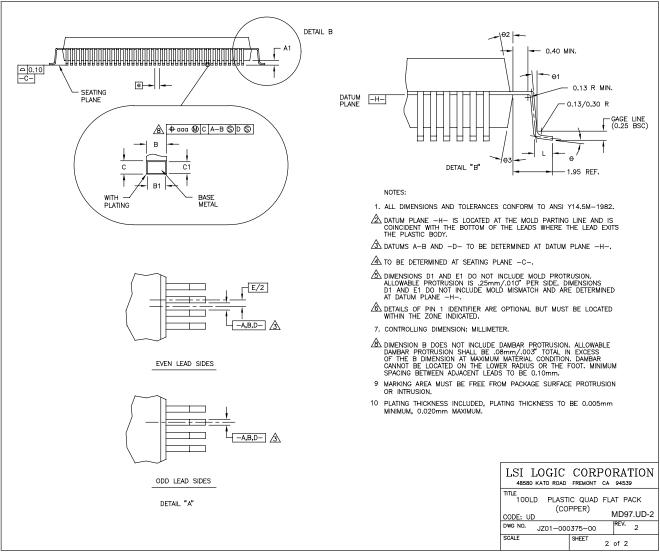
Figure 19 and Figure 20 show the mechanical drawings for the 100-pin PQFP L64734 package.

Figure 19 100-pin PQFP (UD) Mechanical Drawing



Important: This drawing may not be the latest version. For board layout and manufacturing, obtain the most recent engineering drawings from your LSI Logic marketing representative.

Figure 20 100-pin PQFP (UD) Mechanical Drawing (Cont.)



Important: This drawing may not be the latest version. For board layout and manufacturing, obtain the most recent engineering drawings from your LSI Logic marketing representative by requesting the outline drawing for package code UD.

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Sales Offices and Design Resource Centers

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